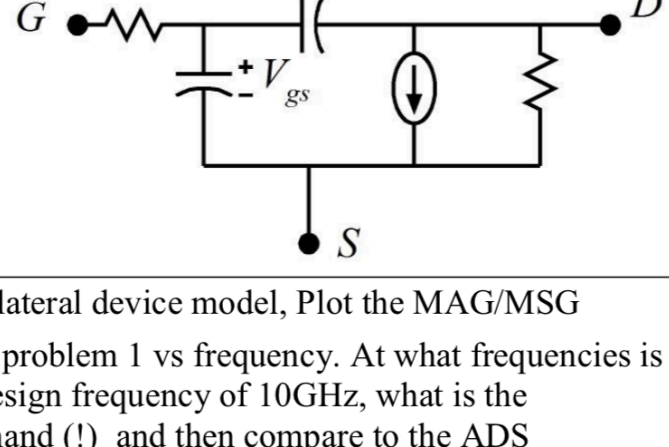


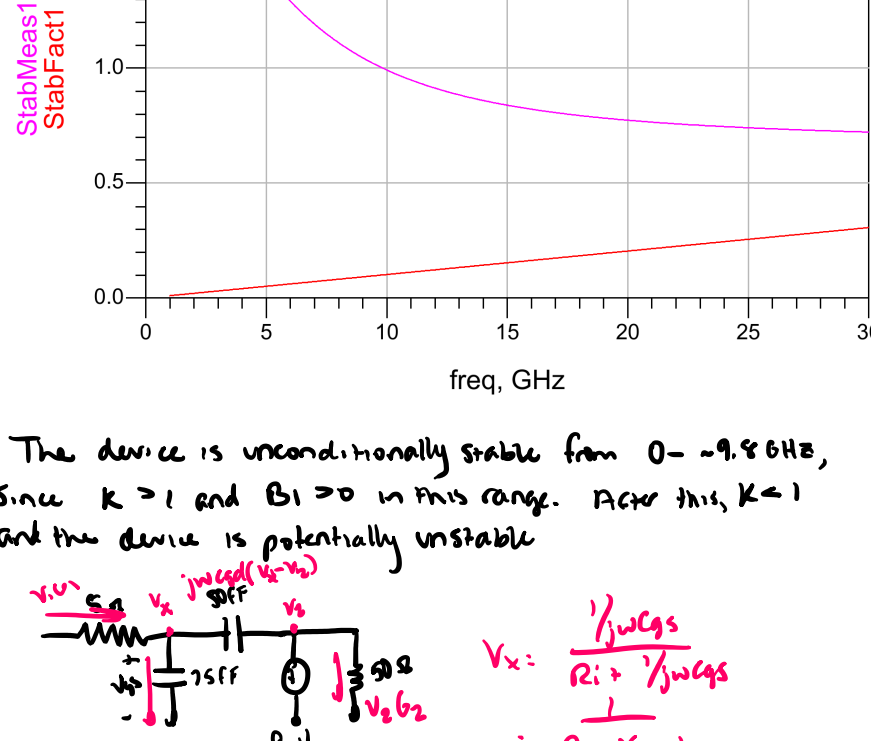
Homework 5

Problem 1:

$g_m = 3mS / \mu m \cdot W_E$
 $R_i = 1.5 / g_m$
 $C_{gs} = 0.5 fF / \mu m \cdot W_E$
 $C_{gd} = 0.75 fF / \mu m \cdot W_E$
 $G_{DS} = 0.2 mS / \mu m \cdot W_E$

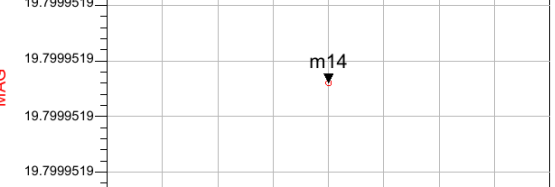


part a) Taking $W_E = 100$ microns for the bilateral device model. Plot the MAG/MSG stability factor K and B1 for the device of problem 1 vs frequency. At what frequencies is the device unconditionally stable? At a design frequency of 10GHz, what is the maximum stable gain? Calculate this by hand (!) and then compare to the ADS simulation.

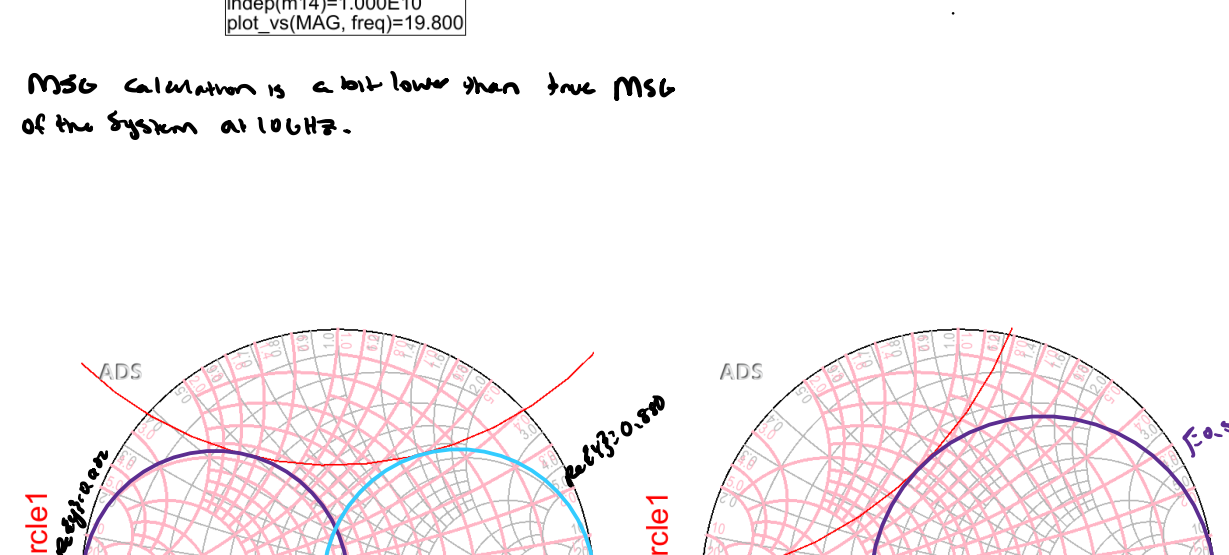


The device is unconditionally stable from 0 - 9.9 GHz, since $K > 1$ and $B_1 > 0$ in this range. After that, $K < 1$ and the device is potentially unstable.

$Y_{21} = g_m + j\omega C_{gd} \left(\frac{G_i}{j\omega C_{gs} + G_i} \right)$
 $= g_m + \frac{j\omega C_{gd} G_i}{j\omega C_{gs} + G_i}$
 $= g_m \left(\frac{j\omega C_{gd} G_i}{j\omega C_{gs} + G_i} + 1 \right)$
 $= g_m \left(\frac{j\omega C_{gd} G_i + j\omega C_{gs} G_i + G_i}{j\omega C_{gs} + G_i} \right)$
 $= g_m \left(\frac{G_i (1 + j\omega C_{gs} + j\omega C_{gd})}{j\omega C_{gs} + G_i} \right)$
 $Y_{12} = -j\omega C_{gd} = 0.0001151 j$
 $\|Y_{21}\| = 0.0021151$
 $\|Y_{12}\| = 0.0001151$
 $MAG = \frac{\|Y_{21}\|}{\|Y_{12}\|} = \frac{0.0021151}{0.0001151} = 18.376$



MAG calculation is a bit lower than true MAG of the system at 10GHz.



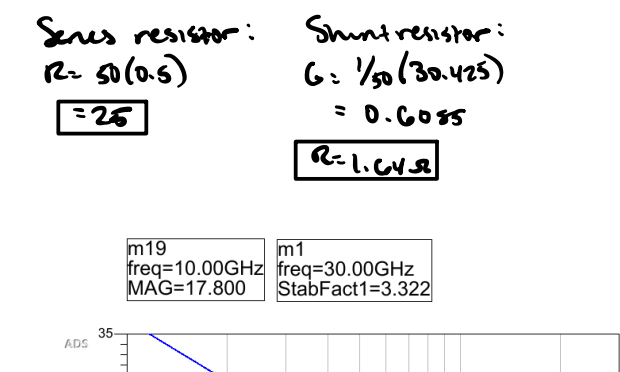
Since $\|S_{11}\|, \|S_{22}\| < 1$ want to constrain smith chart to values outside of $|Γ| = 1$ curve

For source:

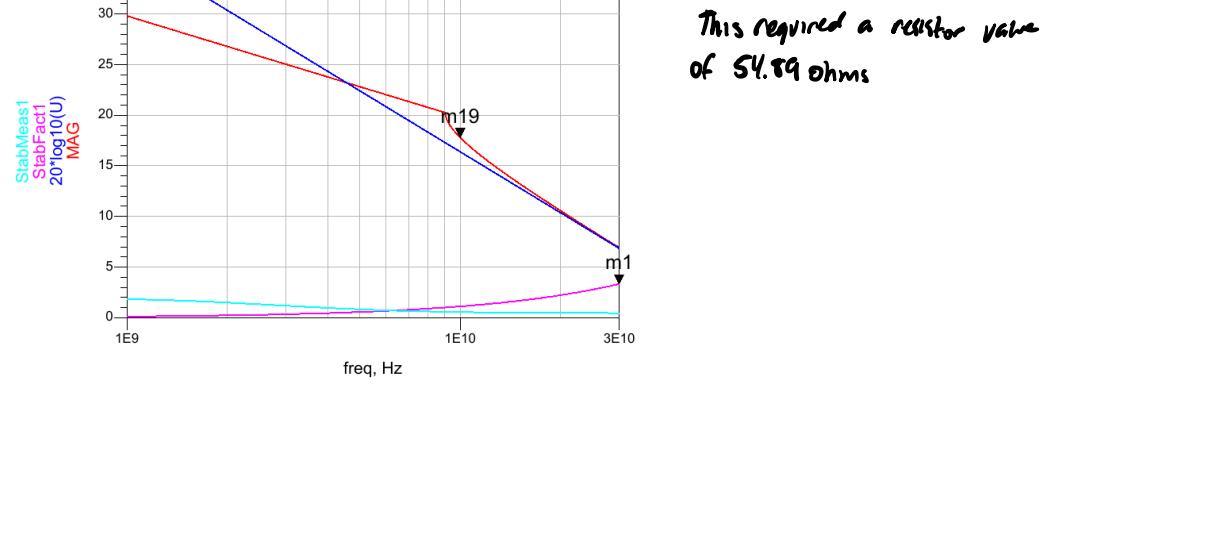
Series resistor: $S_{11} = 0.992$
 $R = 44 \Omega$
 Shunt resistor: $G = 1/50 (0.02)$
 $R = 125 \Omega$

For load:

Series resistor: $S_{22} = 0.992$
 $R = 44 \Omega$
 Shunt resistor: $G = 1/50 (0.02)$
 $R = 125 \Omega$



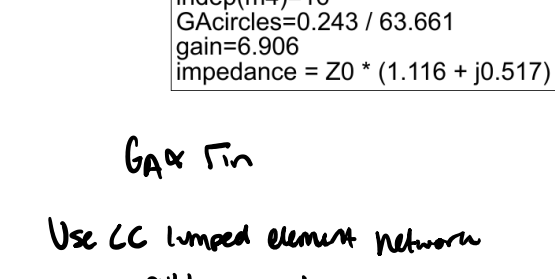
Since MAG was 18.376, our stability for 17.8dB. This required a resistor value of 57.99 ohms.



Gain Γ_{in}

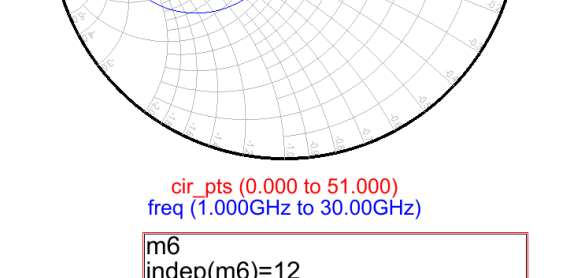
Use LC lumped element network on input to match: $Z_L(1.116 + j0.517) \rightarrow Z_0(1 + j0)$

Match S₂₂ of input network to $Z_0(1.116 + j0.517)$

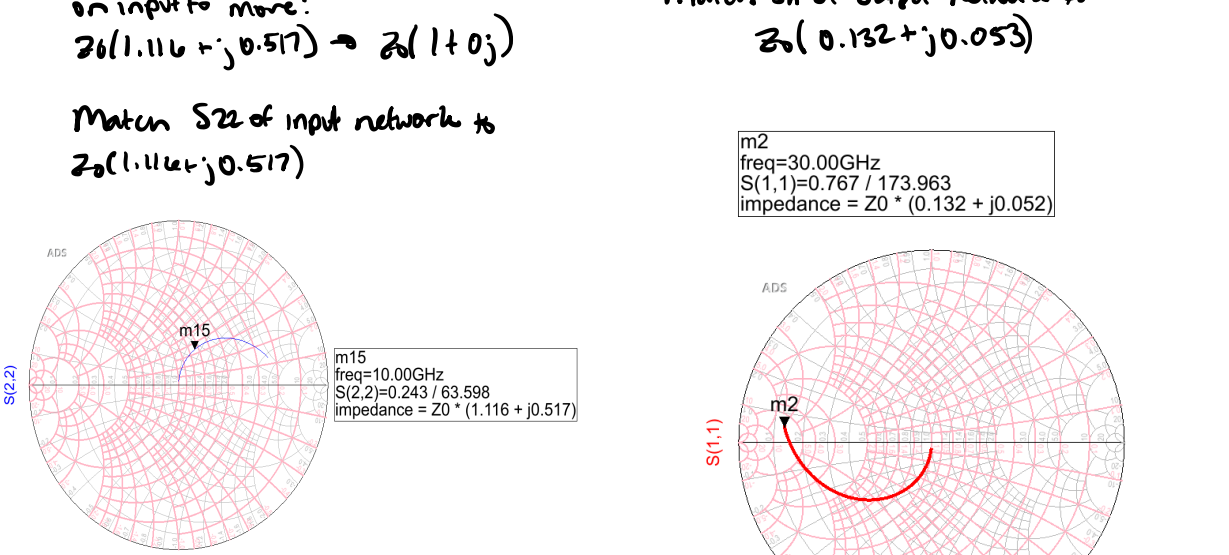


Γ_{out} Match

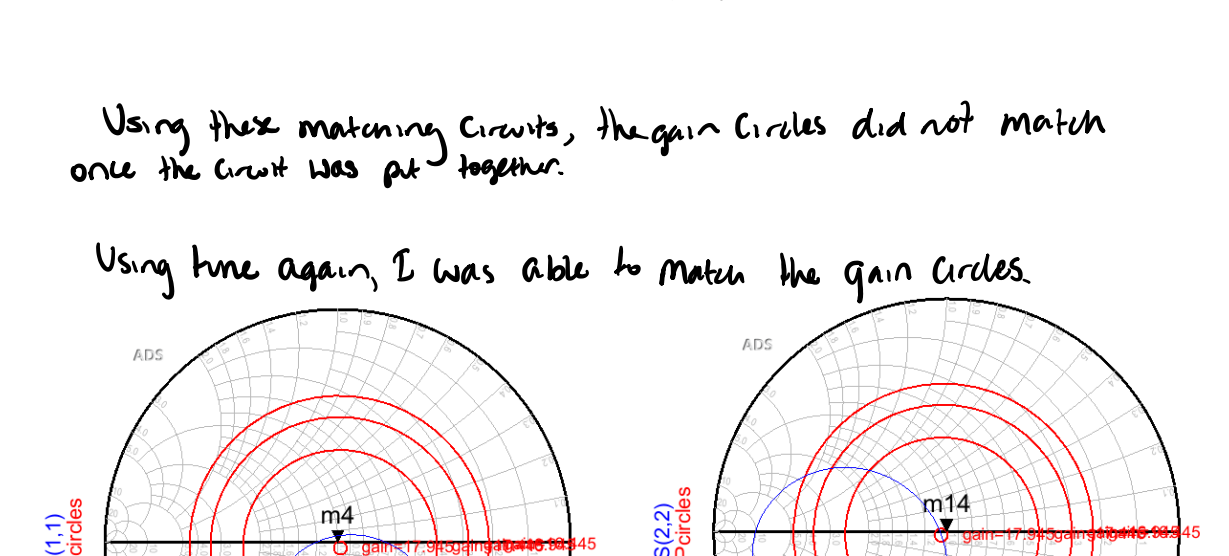
Match S₁₁ of output network to $Z_0(0.132 + j0.053)$



This was incorrectly matched at 30GHz, which was incorrect. I measured again at 10GHz, but this network ended up being inaccurate.



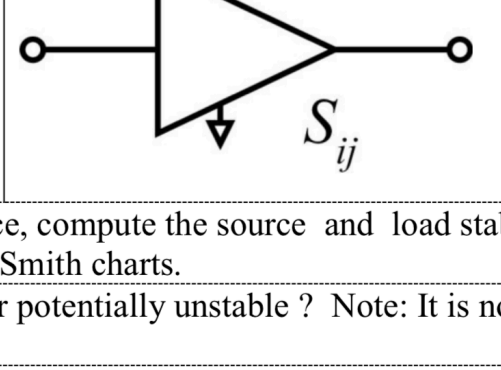
This match was achieved when



At 10GHz, $S_{21} = MSB = 17.72dB$, which is very close to the calculated values of gain after the -2dB overshoot. S_{11} and S_{22} also have singularities at 10 GHz, indicating a correct input and match.

Problem 2: An amplifier has the following S parameters

$S_{11} = S_{22} = 0$
 $S_{12} = 2$
 $S_{21} = 1$

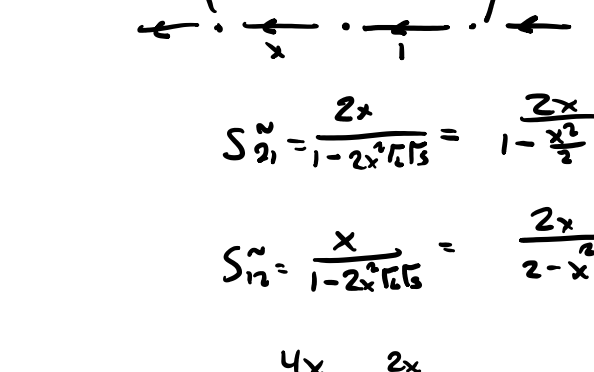


part a) Using a 50 Ohm reference impedance, compute the source and load stability circles, and draw them carefully on separate Smith charts.
 part b) Is the network unconditionally stable or potentially unstable? Note: It is not sufficient to check K alone.
 part c) The network can be stabilized by an attenuator, i.e. a device with $S_{11} = S_{22} = 0$ $S_{21} = X = S_{12}$. What maximum value of X is allowable for unconditional stability?
 part d) After you have stabilized the device, and then matched input and output, what power gain will you obtain?

$S = \begin{bmatrix} 0 & 1 \\ 2 & 0 \end{bmatrix}$

$\Gamma_{in} = \frac{S_{11} + S_{22}\Gamma_L}{1 - S_{12}\Gamma_L}$
 $\Gamma_{in} = 2\Gamma_L$
 $1 - 2\Gamma_L$
 $\frac{1}{2} = \frac{\Gamma_L}{1 - 2\Gamma_L}$
 $\Gamma_L = 1/3$

$\Gamma_{out} = \frac{S_{21}\Gamma_{in}}{1 - S_{22}\Gamma_{in}}$
 $\Gamma_{out} = 1$
 $\frac{1}{2} = \Gamma_{in}$



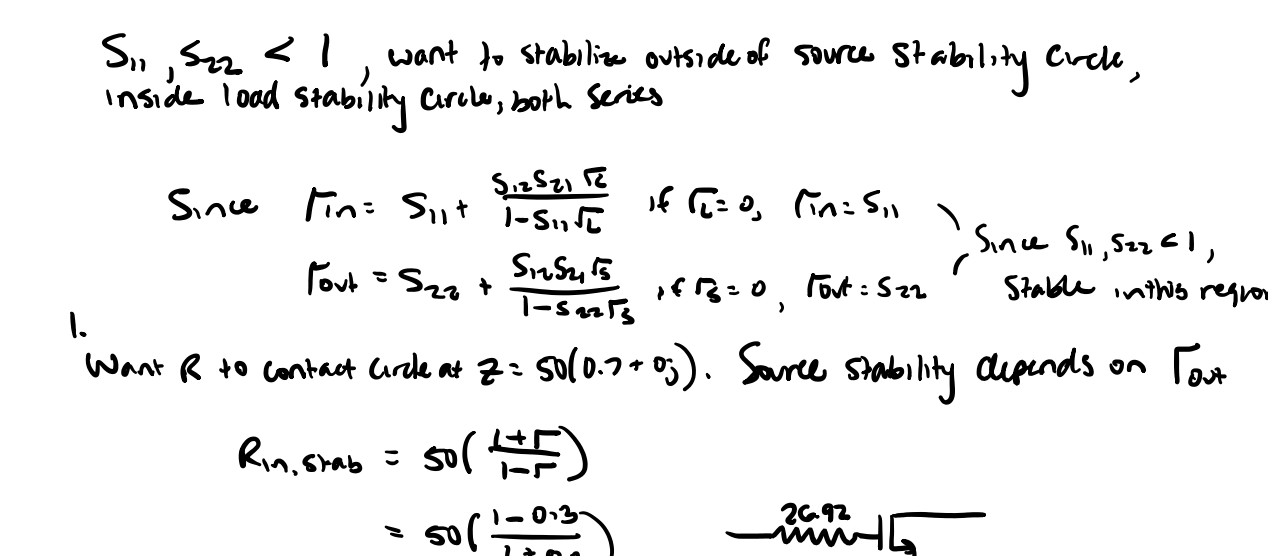
$b) K = \frac{1 - |S_{11}|^2 - |S_{22}|^2}{2|S_{12}S_{21}|}$
 $K = \frac{1 - 0 - 0}{2|2 \cdot 1|} = \frac{1}{4}$
 $K < 1$
 $\text{Det}(S) = |1 - 2| < 1$
 $2 \neq 1$
 The system is potentially unstable because $\text{det}(S) \neq 1$

$c) S_{11} = \frac{1 - X}{1 - 2X}$
 $S_{22} = \frac{2X}{1 - 2X}$
 $S_{21}S_{12} = \frac{4X}{1 - 2X}$
 $\text{Det}(S) < 1$
 $\| \frac{S_{21}}{1 - S_{22}\Gamma_L} \| < 1$
 $\frac{2}{1 - 2X} < 2 - X^2$
 $2\sqrt{2}X < 2 - X^2$
 $X^2 + 2\sqrt{2}X - 2 < 0$
 Use positive soln:
 $X = 0.686$ for unconditional stability

$d) \text{ After device is stabilized, msg: } \| \frac{S_{21}}{1 - S_{22}\Gamma_L} \| = \| \frac{2}{1} \| = 2$

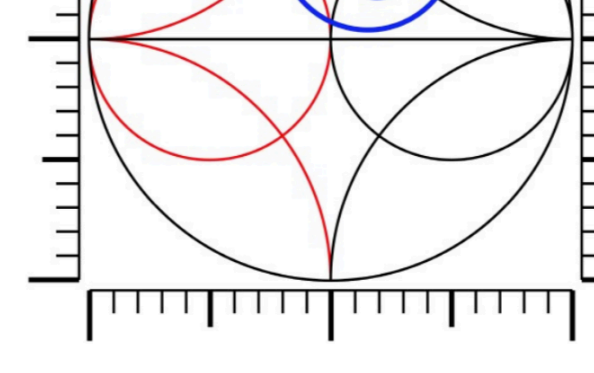
Problem 3:

Source stability circle load stability circle

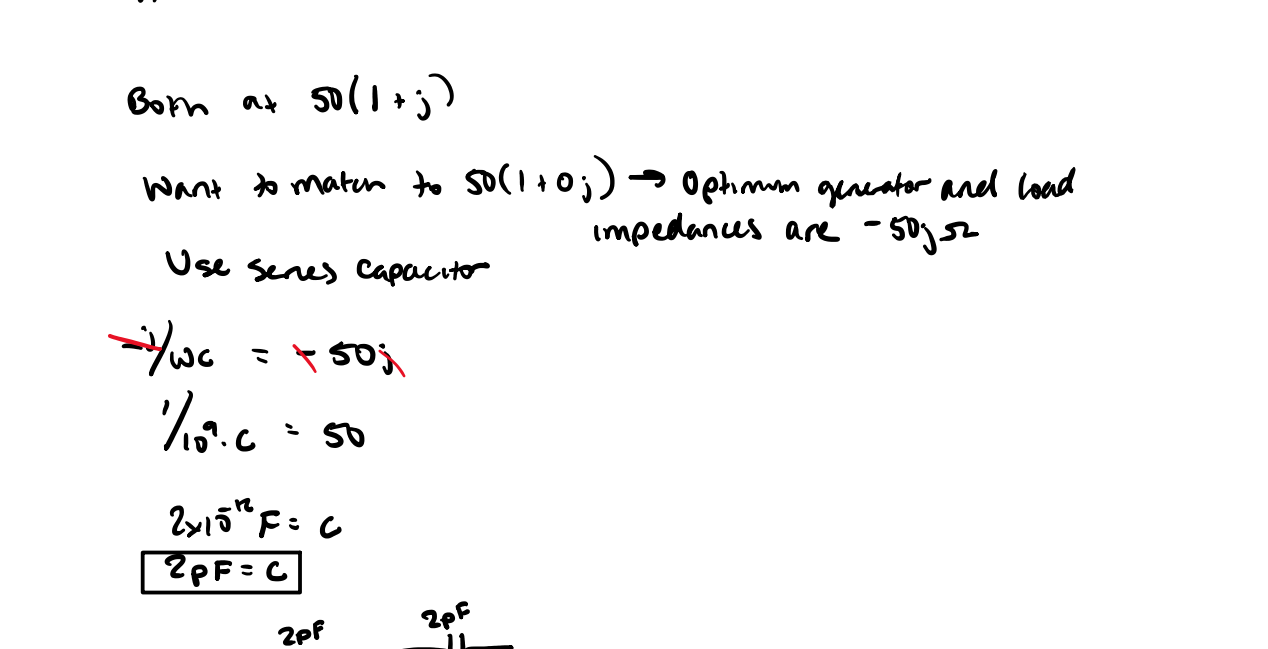


Given that $S_{11} = 0.5$ and $S_{22} = 0.9$ at 10 GHz, draw two stabilization circuits in the boxes below, giving element values

$S_{11}, S_{22} < 1$, want to stabilize outside of source stability circle, inside load stability circle, both series.
 Since $\Gamma_{in} = S_{11} + \frac{S_{21}S_{12}\Gamma_L}{1 - S_{22}\Gamma_L}$ if $\Gamma_L = 0$, $\Gamma_{in} = S_{11}$
 $\Gamma_{out} = S_{22} + \frac{S_{21}S_{12}\Gamma_{in}}{1 - S_{11}\Gamma_{in}}$, if $\Gamma_{in} = 0$, $\Gamma_{out} = S_{22}$ Since $S_{11}, S_{22} < 1$,
 1. Want R to contact circle at $Z = 50(0.7 + j0)$. Source stability depends on Γ_{out}
 $R_{in,stab} = 50 \left(\frac{1 + \Gamma_{out}}{1 - \Gamma_{out}} \right) = 50 \left(\frac{1 + 0.9}{1 - 0.9} \right) = 20.925 \Omega$
 2. Want R to contact circle at $Z = 50(0.1 + j0)$
 $R_{out,stab} = 50 \left(\frac{1 + \Gamma_{in}}{1 - \Gamma_{in}} \right) = 50 \left(\frac{1 + 0.5}{1 - 0.5} \right) = 33.33 \Omega$

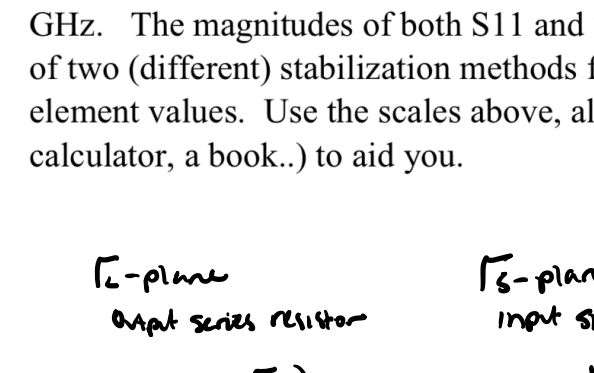


Problem 4: The charts below use 50 Ohm normalization.

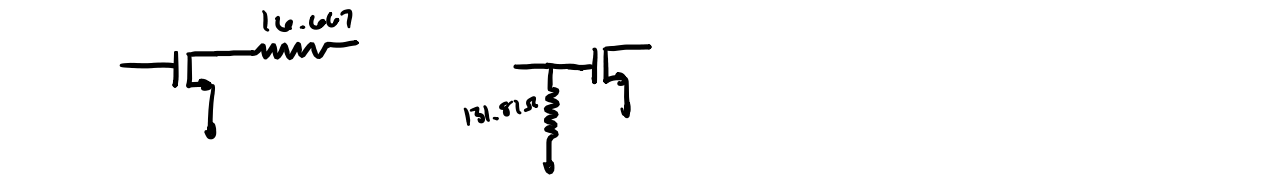


At 10 GHz, a MOSFET in common-source mode operating and available gain circles as shown. Find the optimum generator and load impedances (in complex Ohms). Design LC matching networks to match to a 50 Ohm generator and load.

$G_a \rightarrow \text{Source}$
 $G_{op} \rightarrow \text{load}$
 Both as $50(1 + j)$
 Want to match to $50(1 + j) \rightarrow$ Optimum generator and load impedances are -50jΩ
 Use series capacitor
 $\frac{1}{j\omega C} = -50j$
 $\frac{1}{\omega C} = 50$
 $2\pi \cdot 10^9 \cdot C = 50$
 $C = 7.96 \text{ pF}$



Problem 5: The charts below use 50 Ohm normalization.



A FET in common-source configuration has the stability circles as shown above at 20 GHz. The magnitudes of both S_{11} and S_{22} are less than 1. Draw (two) circuit diagrams of two (different) stabilizations methods for the transistor, giving required numerical element values. Use the scales above, along with a straight edge (edge of paper, a calculator, a book...) to aid you.

Γ_L -plane
 input series resistor
 $R_{stab} = \frac{1 + \Gamma_{in}}{1 - \Gamma_{in}} Z_0 = \frac{1 + 0.5}{1 - 0.5} Z_0 = 16.667 \Omega$
 $C_{stab} = 0.00259$
 $R_{stab} = 13.817 \Omega$

